**IGBT Modules** 

### Power Module (V series) 1200V / 150A / 2-in-1 package

#### ■ Features

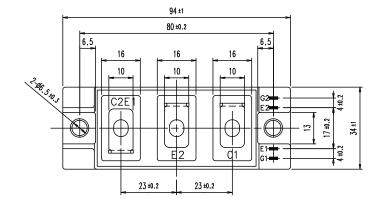
AC-switch
High speed switching
Voltage drive
Low Inductance module structure

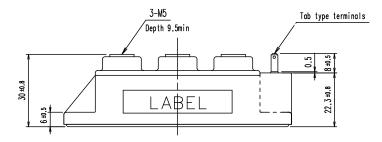
### ■ Applications

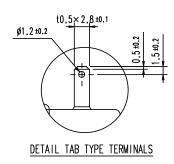
AC-switch for UPS,PCS and etc.

### ■ Outline drawing (Unit:mm)



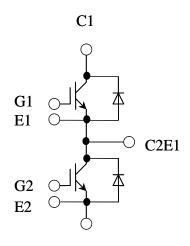






Weight: 180g (typ.)

### ■ Equivalent circuit



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### ■ Absolute maximum ratings (at T<sub>C</sub>= 25°C unless otherwise specified)

Items		Symbols	Conditions	Maximum ratings	Units	
Collector-Emitter voltage		V <sub>CES</sub>		1200	V	
Gate-Emitte	r voltage	V <sub>GES</sub>		±20	V	
-		I <sub>C</sub>	Continuous T <sub>C</sub> =100°C	150		
Collector cu	rront	I <sub>C</sub> pulse	1ms	300	Α	
Collector cui	nent	-1 <sub>C</sub>		150	_ A	
		-/ c pulse	1ms	300		
Collector power dissipation		Pc	1 device	785	W	
Junction temperature		T <sub>i</sub>		175		
Operating junction temperature		τ		150		
(under switching conditions)		$T_{jop}$		150	°C	
Case temperature		T <sub>c</sub>		125		
Storage temperature		$T_{\rm stg}$		-40 ~ 125		
Isolation	Between terminal and copper base		A.C. 1 in	2500	\/AC	
voltage	(*1)	$V_{iso}$	AC: 1min.	2500	VAC	
Screw	Mounting	-	M5 or M6	3.0~5.0	N m	
torque	Terminals	-	M5	2.5~5.0	)	

<sup>(\*1)</sup> All terminals should be connected together when isolation test will be done.

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#### ■ Electrical characteristics (at $T_j$ = 25°C unless otherwise specified)

#### NOTICE:

The external gate resistance ( $R_g$ ) shown below is one of our recommend value for the purpose of minimum switching loss. However the optimum  $R_g$  depends on circuit configuration and/or environment. We recommend that the  $R_g$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

ltomo	Cumbala	Conditio	no	Characteristics		Units	
Items	Symbols	Conditions		min.	typ.	max.	Units
Zero gate voltage collector current	I <sub>CES</sub>	V <sub>GE</sub> =0V,V <sub>CE</sub> =1200V		-	-	1.0	mA
Gate-Emitter leakage current	I <sub>GES</sub>	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	200	nA
Gate-Emitter threshold voltage	$V_{GE(th)}$	V <sub>CE</sub> =20V,I <sub>C</sub> =150mA		6.0	6.5	7.2	V
	V <sub>CE(sat)</sub>		T <sub>j</sub> =25°C	-	2.05	2.50	
		$V_{GE}$ =15V, $I_{C}$ =150A	T <sub>j</sub> =125°C	-	2.35	-	
Collector-Emitter	(terminal)		T <sub>j</sub> =150°C	-	2.40	-	V
saturation voltage	V		T <sub>i</sub> =25°C	-	1.75	2.20	7 <b>v</b>
	V <sub>CE(sat)</sub>	$V_{\rm GE} = 15 \text{V}, I_{\rm C} = 150 \text{A}$ $T_{\rm i} = 125 ^{\circ} \text{C}$ -	2.05	-	1		
	(chip)		T <sub>j</sub> =150°C	-	2.00	-	-
Internal gate resistance	R <sub>g(int)</sub>	-		-	5	-	Ω
Input capacitance	C ies	V <sub>CE</sub> =10V, V <sub>GE</sub> =0V, j	f=1MHz	-	12.6	-	nF
	t on			-	600	-	
Turn-on time	t <sub>r</sub>	$V_{\rm CC}$ =600V, $I_{\rm C}$ =150A, $V_{\rm GE}$ =±15V, - 200 - $R_{\rm g}$ =1.1 $\Omega$ , $T_{\rm j}$ =150°C, $L_{\rm s}$ =30nH - 600		-	200	-	nsec
	t <sub>r(i)</sub>			-	50	-	
Turn-off time	t off			-	1		
Turn-on time	$t_{f}$		-	40	-	1	
	V <sub>F</sub>		T <sub>i</sub> =25°C	-	1.85	2.30	
	-	$V_{GE} = 0V, I_{F} = 150A$	T <sub>i</sub> =125°C	-	2.00	-	
Forward on voltage	(terminal)		T <sub>j</sub> =150°C	-	1.95	-	V
Forward on voltage	V <sub>F</sub>	$V_{\text{GE}} = 0 \text{V}, I_{\text{F}} = 150 \text{A}$ $T_{\text{j}} = 25^{\circ} \text{C}$ - 1.70 $T_{\text{j}} = 125^{\circ} \text{C}$ - 1.85	1.70	2.15	V		
			-	1.85	-	]	
	(chip)		T <sub>j</sub> =150°C	-	1.80	-	
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> =150A		-	150	-	nsec

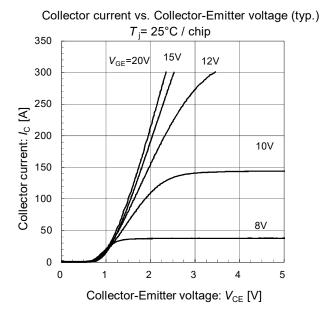
#### ■ Thermal resistance characteristics

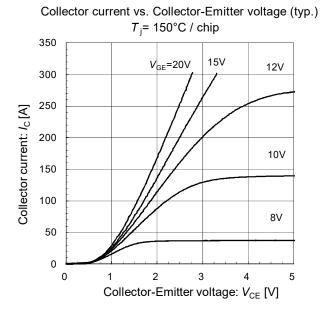
Items	Symbols	Conditions	Characteristics			Units
items	Symbols	min.		typ.	max.	Ullits
Thermal resistance	D	IGBT	-	-	0.19	
(1device)	R <sub>th(j-c)</sub>	FWD	-	-	0.31	°C/W
Contact thermal resistance	D	with thermal compound		0.050		C/VV
(1device) (*1)	R <sub>th(c-f)</sub>	with thermal compound	-	0.050	-	

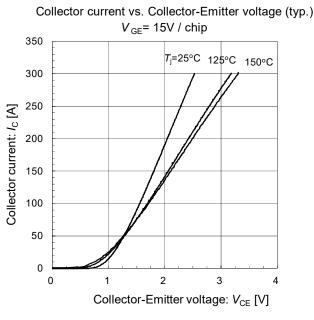
<sup>(\*1)</sup> This is the value which is defined mounting on the additional cooling fin with thermal compound.

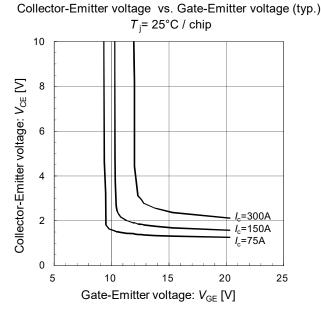


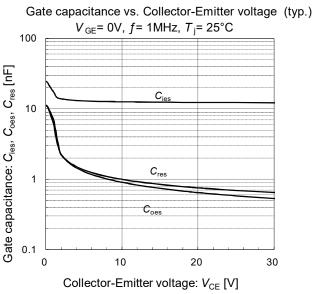
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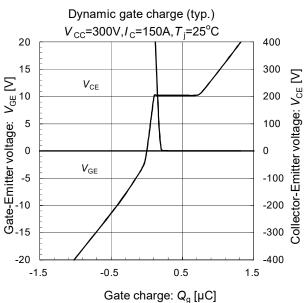






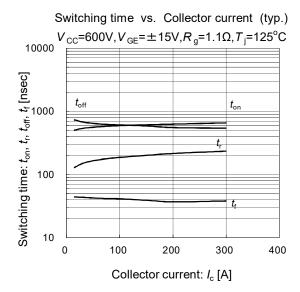


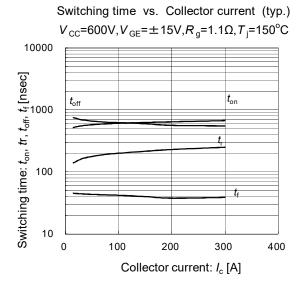


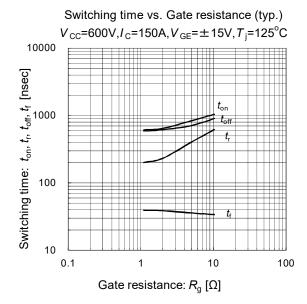


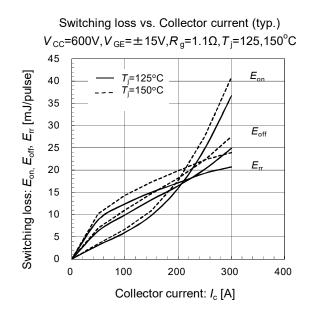


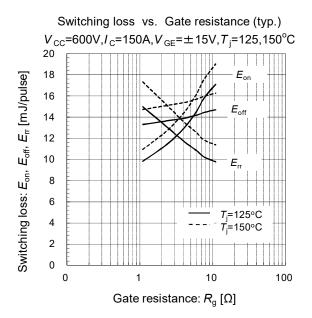
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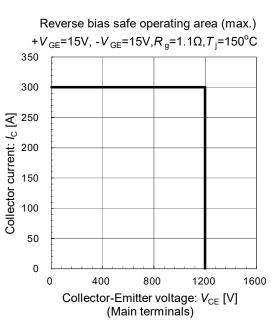






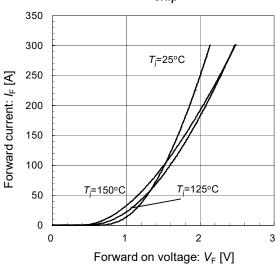




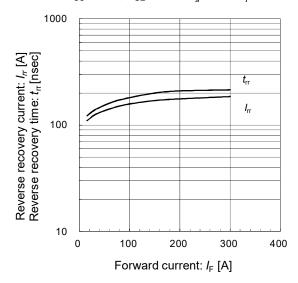


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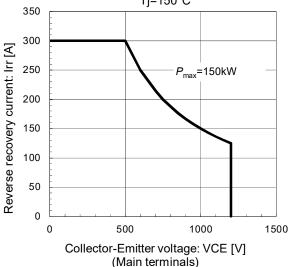
Forward current vs. Forward voltage (typ.)



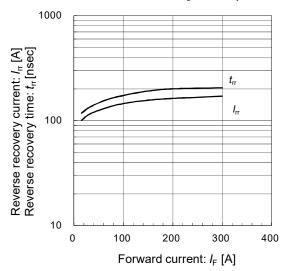
Reverse recovery characteristics (typ.)  $V_{\rm CC}$ =600V,  $V_{\rm GE}$ =±15V,  $R_{\rm q}$ =1.1 $\Omega$ ,  $T_{\rm i}$ =150°C



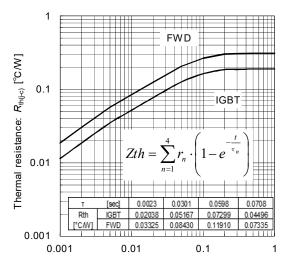
FWD safe operating area (max.) Tj=150°C 350



Reverse recovery characteristics (typ.)  $V_{\rm CC}$ =600V,  $V_{\rm GE}$ = ±15V,  $R_{\rm q}$ =1.1 $\Omega$ ,  $T_{\rm i}$ =125°C



#### Transient thermal resistance (max.)



Pulse width : Pw [sec]



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